



# CMOS Clock Generator – 74ACT3301

Monolithic crystal controlled CMOS oscillator in bare die form

Rev 1.0  
07/06/18

## Description

The 74ACT3301 is a crystal controlled CMOS oscillator requiring a minimum of external components and is designed for Clock Generation and Support applications up to 110 MHz. The device is highly versatile, providing selectable output divide ratios, multiple crystal drive levels and selectable rise and fall timing options. The circuit is designed to operate over a wide frequency range using fundamental model or overtone crystals. The device is a direct electrical and mechanical replacement for the obsolete 74ACT3301 produced by National Semiconductor and Fairchild Semiconductor.

## Features:

- Crystal frequency operation range:
  - fundamental: 10 MHz to 100 MHz typical
  - 3rd or 5th overtone: 10 MHz to 85 MHz
- Programmable oscillator drive
- Selectable fast output edge rates
- Output symmetry circuit to adjust 50% duty cycle point between CMOS and TTL levels
- Output current drive of 48 mA for  $I_{OL}/I_{OH}$
- Output has high speed short circuit protection
- Basic oscillator type: Pierce

## Ordering Information

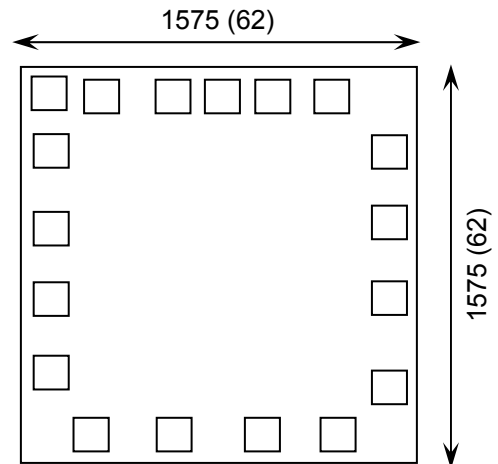
The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection

For High Reliability versions of this product please see

[54ACT3301](#)

## Die Dimensions in $\mu\text{m}$ (mils)



## Supply Formats:

- Default – Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness  $\leftrightarrow$  460 $\mu\text{m}$ (18 Mils) – On request
- Assembled into Ceramic Package – On request

## Mechanical Specification

Die Size (Unsawn)	1575 x 1575 62 x 62	$\mu\text{m}$ mils
Minimum Bond Pad Size	100 x 100 4 x 4	$\mu\text{m}$ mils
Die Thickness	460 ( $\pm 10$ ) 18.11 ( $\pm 0.39$ )	$\mu\text{m}$ mils
Top Metal Composition	Al 1%Si 1.1 $\mu\text{m}$	
Back Metal Composition	N/A – Bare Si	

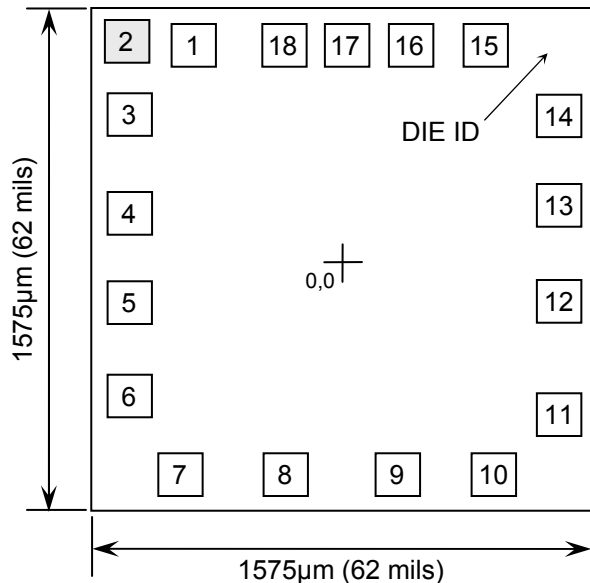




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## Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)	
		X	Y
1	OSC_OUT	-436	630
2	NOT USED	-639	639
3	XTAL - 5	-624	429
4	XTAL - 10	-624	135
5	OEL	-626	-124
6	OEH	-626	-394
7	OSCLO_1	-493	-637
8	GND	-178	-637
9	OUT	142	-637
10	V <sub>CC</sub>	421	-637
11	TRF	631	-466
12	DIVA	631	-125
13	OSC_DR	631	155
14	DIVB	631	421
15	OSCLO_2	419	631
16	GNDQ	199	630
17	OSC_IN	9	630
18	XTAL - 20	-167	630
CHIP BACK POTENTIAL IS FLOATING			

## Truth Tables

### DIVISION SELECTION

DIVB	DIVA	OEL	OEH	DIVIDER OUTPUT
V <sub>1/2</sub>	0 / F	X	X	Divide-by 1
1	0 / F	0	1	Divide-by 2
0	0 / F	0	1	Divide-by 4
V <sub>1/2</sub>	1	0	1	Divide-by 8
1	1	0	1	Divide-by 16
0	1	0	1	Divide-by 32
X	X	1	X	Output Reset High at Re-enable
X	X	X	0	Output Reset High at Re-enable

### DRIVE SELECTION

OSC_DR	OSC_OUT DRIVE
0	Low
1	Medium
V <sub>1/2</sub>	High

### INPUT LEVEL

1	High voltage
0	Low voltage
V <sub>1/2</sub>	V <sub>CC/2</sub>
F	Floating
X	Irrelevant

### RISE AND FALL TIME SELECTION

OSC_DR	DIV	TRF	RISE / FALL TIME (ns)
V <sub>1/2</sub>	N	0 / F	2
V <sub>1/2</sub>	N	1	<2
V <sub>1/2</sub>	Y	0 / F	4
V <sub>1/2</sub>	Y	1	2
0 / 1	X	0 / F	4
0 / 1	X	1	2





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## Configuration Options

DIVIDE	ENABLE	DRIVE	OUTPUT RISE / FALL TIME (ns)
1,2,4	OEH	L, M, H	2, 4
1,2,4	OEH	H	2, 4
8, 16, 32	OEH	H	4
8, 16, 32	OEH	L, M, H	4
1,2,4	OEL	H	1, 2
4	OEH	H	4
32	OEH	H	4
1,2,4	OEH	H	1, 2
1,2,4	OEL	L, M, H	2, 4

Each configuration comprises one output with the choice of selected frequency divide, output enable, crystal drive and output rise/fall time.

Crystal drive options:

- L = Low drive
- M = Medium drive
- H = High drive.

## Pad Descriptions

### INPUTS

**OSC IN** (Pad 17) - Input to Oscillator Inverter. The output of the crystal would be connected here.

### CONTROL INPUTS

**DIVA** (Pad 12) - Input used to select Binary Divide-By Option. This pin has CMOS compatible input levels.

**DIVB** (Pad 14) - 3 Level input used to select Binary Divide-By value.

**OSC\_DR** (Pad 13) - 3 Level input pin that selects Oscillator Drive Level.

**OEH** (Pad 6) - Active High Three-state enable pin. This pin pulls to a high value when left floating and three-states the output when forced low. This pin has TTL compatible input levels.

**OEL** (Pad 5) - Active Low Three-state enable pin. This pin pulls to a low value when left floating and three-states the output when forced high. This pin has TTL compatible input levels.

**TRF** (Pad 11) - Rise and Fall time override pin

### OUTPUTS

**OUT** (Pad 9) - This pin is the main clock output on the device.

**OSC\_OUT** (Pad 1) - Resistive buffered output of the Oscillator inverter

### OTHER PADS

**OSCLO\_1** (Pad 7) - The Oscillator Low pin is the ground for the Oscillator.

**OSCLO\_2** (Pad 15) - This pin is the same signal as OSCLO\_1 and provided as an alternative connection for hybrid assemblies.

**VCC** (Pad 10) - The power pin for the chip.

**GND** (Pad 8) - The ground pin for all sections of the circuitry except the oscillator and oscillator related circuitry.

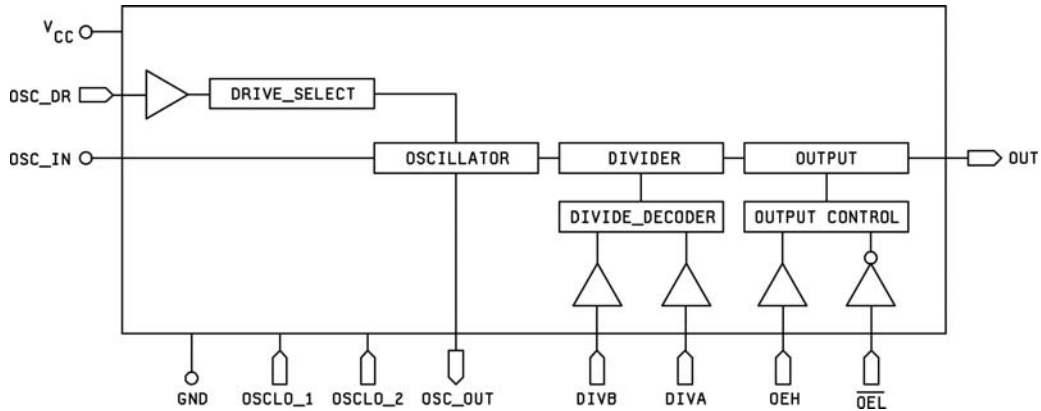




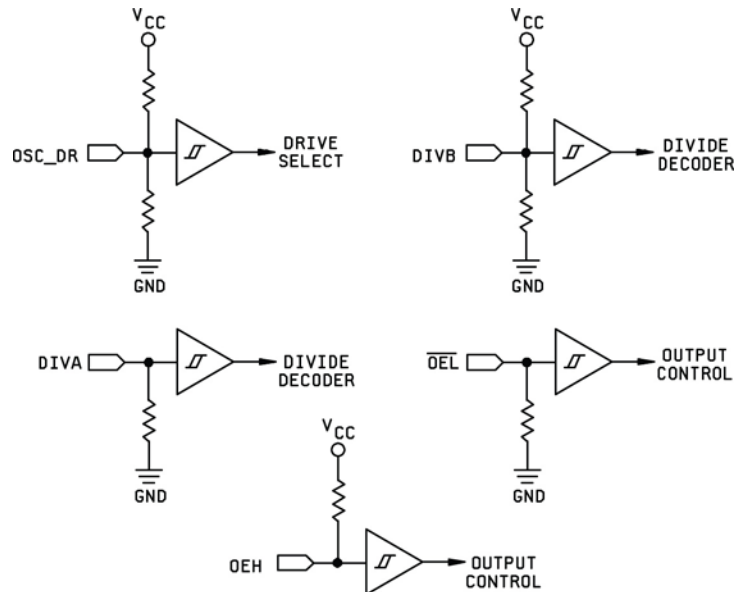
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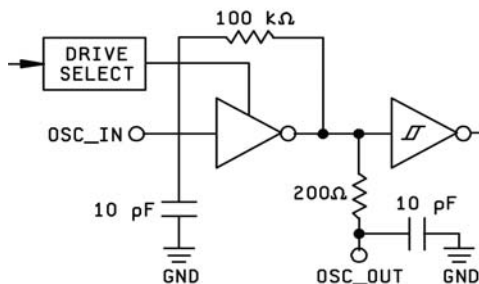
## Logic Diagrams



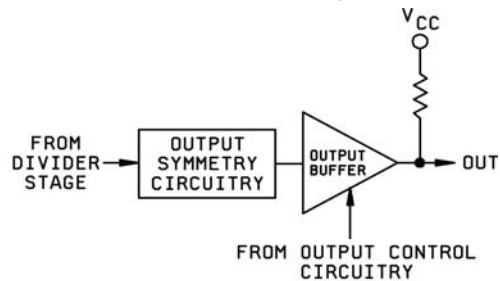
### Input Stage



### Oscillator Stage



### Output Stage





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## Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5 to +7.0	V
Input Voltage Range	$V_{IN}$	-0.5 to +7.0	V
Output Voltage Range	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	±9	mA
Output Diode Current	$I_{OK}$	±20	mA
Output Source or Sink Current	$I_{OUT}$	±70	mA
Storage Temperature	$T_{STG}$	-65 to +150	°C
Power Dissipation in Still Air <sup>2</sup>	$P_D$	500	mW

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.
2. Assembled in 16 lead ceramic flatpack

## Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNITS
Operating Temperature	$T_J$	-40	+85	°C
DC Supply Voltage	$V_{CC}$	+4.5	+5.5	V
Input voltage range	$V_{IN}$	0	+5.5	V
Output Voltage Range	$V_{OUT}$	0	$V_{CC}$	V
Maximum low level input voltage	$(V_{IL1})$ (OE $\bar{H}$ , $\bar{O}E\bar{L}$ )	-	0.8	V
Minimum high level input voltage	$(V_{IH1})$ (OE $\bar{H}$ , $\bar{O}E\bar{L}$ )	-	2	V
Maximum low level input voltage	$(V_{IL2})$ (DIVA)	30% $V_{CC}$		V
Minimum high level input voltage	$(V_{IH2})$ (DIVA)	70% $V_{CC}$		V
Maximum low level input voltage	$(V_{IL3})$ (OSC_DR, DIVB)	10% $V_{CC}$		V
One-half input voltage level	$(V_{1/2})$ (OSC_DR, DIVB)	50% $V_{CC}$		V
Minimum high level input voltage	$(V_{IH3})$ (OSC_DR, DIVB)	90% $V_{CC}$		V
Maximum high level output current	$I_{OH}$	-	-48	mA
Maximum low level output current	$I_{OL}$	-	+48	mA

## DC Electrical Characteristics (+4.5V ≤ $V_{CC}$ ≤ +5.5 V, -40°C ≤ $T_J$ ≤ +85°C unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
Minimum high level input voltage. TTL (OE $\bar{H}$ , $\bar{O}E\bar{L}$ )	$V_{IH1}$	$V_{CC} = 4.5V$	2	-	-	V
		$V_{CC} = 5.5V$	2	-	-	
Maximum low level input voltage. TTL (OE $\bar{H}$ , $\bar{O}E\bar{L}$ )	$V_{IL1}$	$V_{CC} = 4.5V$	-	-	0.8	V
		$V_{CC} = 5.5V$	-	-	0.8	





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PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS	
			MIN	TYP	MAX		
Minimum high level input voltage. CMOS (DIVA)	V <sub>IH2</sub>	V <sub>CC</sub> = 4.5V	3.15	-	-	V	
		V <sub>CC</sub> = 5.5V	3.85	-	-		
Maximum low level input voltage. CMOS (DIVA)	V <sub>IL2</sub>	V <sub>CC</sub> = 4.5V	-	-	1.35	V	
		V <sub>CC</sub> = 5.5V	-	-	1.65		
Min. high level input voltage. TRI-STATE (DIVB, OSC_DR)	V <sub>IH3</sub>	V <sub>CC</sub> = 4.5V	4.05	-	-	V	
		V <sub>CC</sub> = 5.5V	4.95	-	-		
Max. low level input voltage. TRI-STATE (DIVB, OSC_DR)	V <sub>IL3</sub>	V <sub>CC</sub> = 4.5V	-	-	0.45	V	
		V <sub>CC</sub> = 5.5V	-	-	0.45		
½ level input voltage. TRI-STATE (DIVB, OSC_DR)	V <sub>½</sub>	V <sub>CC</sub> = 4.5V	1.8	-	2.70	V	
		V <sub>CC</sub> = 5.5V	2.2	-	3.30		
High level output voltage (OUT)	V <sub>OH1</sub>	OEH = V <sub>IH1</sub> , DIVA = V <sub>IH2</sub> , OEL = GND, DIVB = V <sub>IH3</sub> or V <sub>½</sub> , I <sub>OH</sub> = -50 µA	V <sub>CC</sub> = 4.5V	4.40	25°C	-	V
					4.49		
			V <sub>CC</sub> = 5.5V	5.40	25°C	-	
					5.49		
OEH, DIVA, DIVB = V <sub>CC</sub> ; OEL = GND; I <sub>OH</sub> = -48 mA	V <sub>CC</sub> = 4.5V	3.76	-	-	V		
	V <sub>CC</sub> = 5.5V	4.76	-	-			
OEH, DIVA, DIVB = V <sub>CC</sub> , OEL = GND, <sup>3</sup> I <sub>OH</sub> = -75 mA <sup>3</sup>	V <sub>CC</sub> = 5.5V	3.85	-	-	V		
High level output voltage, low drive (OSC_OUT)	V <sub>OH2</sub>	OSC_IN, OSC_DR = 0V, I <sub>OH</sub> = -150 µA	V <sub>CC</sub> = 4.5V	3.46	-	-	V
			V <sub>CC</sub> = 5.5V	4.46	-	-	
High level output voltage, medium drive (OSC_OUT)	V <sub>OH3</sub>	OSC_IN = 0V, OSC_DR = V <sub>CC</sub> I <sub>OH</sub> = -600 µA	V <sub>CC</sub> = 4.5V	3.46	-	-	V
			V <sub>CC</sub> = 5.5V	4.46	-	-	
High level output voltage, high drive (OSC_OUT)	V <sub>OH4</sub>	OSC_IN = 0V, I <sub>OH</sub> = -1 mA	OSC_DR = 2.25V	3.46	-	-	V
			OSC_DR = 2.75V	4.46	-	-	
Minimum dynamic output current	I <sub>OH</sub>	V <sub>OH</sub> = 3.85V	V <sub>CC</sub> = 5.5V	-75	-	-	mA

3. Transmission driving tests are performed at V<sub>CC</sub> = 5.5 V with a 2 ms duration maximum.





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PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS	
			MIN	TYP	MAX		
Low level output voltage (OUT)	V <sub>OL1</sub>	OEH = V <sub>CC</sub> , DIVA = V <sub>IL2</sub> , OEL = V <sub>IL1</sub> , DIVB = V <sub>IL3</sub> or V <sub>1/2</sub> , I <sub>OL</sub> = 50 μA	V <sub>CC</sub> = 4.5V	-	-	0.10	V
		V <sub>CC</sub> = 5.5V	-	-	0.10		
		OEH = V <sub>CC</sub> , DIVA, DIVB = GND, OEL = GND, I <sub>OL</sub> = 48 mA	V <sub>CC</sub> = 4.5V	-	-	0.44	V
		V <sub>CC</sub> = 5.5V	-	-	0.44		
		OEH = V <sub>CC</sub> , DIVA, DIVB = GND, OEL = GND, I <sub>OL</sub> = 75 mA <sup>3</sup>	V <sub>CC</sub> = 5.5V	-	-	1.65	V
Low level output voltage, low drive (OSC_OUT)	V <sub>OL2</sub>	OSC_IN = V <sub>CC</sub> , OSC_DR = 0V, I <sub>OL</sub> = 150 μA	V <sub>CC</sub> = 4.5V	-	-	0.74	V
			V <sub>CC</sub> = 5.5V	-	-	0.74	
Low level output voltage, medium drive (OSC_OUT)	V <sub>OL3</sub>	OSC_IN, OSC_DR = V <sub>CC</sub> , I <sub>OL</sub> = 600 μA	V <sub>CC</sub> = 4.5V	-	-	0.74	V
			V <sub>CC</sub> = 5.5V	-	-	0.74	
Low level output voltage, high drive (OSC_OUT)	V <sub>OL4</sub>	OSC_IN = V <sub>CC</sub> , I <sub>OL</sub> = 1 mA	OSC_DR = 2.25V	-	-	0.74	V
			OSC_DR = 2.75V	-	-	0.74	
Minimum Dynamic Output Current	I <sub>OL</sub>	V <sub>OL</sub> = 1.65V	V <sub>CC</sub> = 5.5V	75	-	-	mA
Positive input clamp voltage	V <sub>IC+</sub>	I <sub>IN</sub> = 9 mA	V <sub>CC</sub> = 4.5V	-	-	5.7	V
Negative input clamp voltage	V <sub>IC-</sub>	I <sub>IN</sub> = -9 mA	V <sub>CC</sub> = 4.5V	-	-	-1.2	V
Input current high (DIVB, OSC_DR)	I <sub>IH</sub>	V <sub>IN</sub> = 5.5V	V <sub>CC</sub> = 5.5V	200	-	380	μA
Input current low (DIVB, OSC_DR)	I <sub>IL</sub>	V <sub>IN</sub> = 0V	V <sub>CC</sub> = 5.5V	-200	-	-380	μA
Input current high (OEL)	I <sub>IH</sub>	V <sub>IN</sub> = 5.5V	V <sub>CC</sub> = 5.5V	85	-	175	μA
Input current low (OEH)	I <sub>IL</sub>	V <sub>IN</sub> = 0V	V <sub>CC</sub> = 5.5V	-85	-	-175	μA
Input current low (DIVA, OEL)	I <sub>IL</sub>	V <sub>IN</sub> = 0V	V <sub>CC</sub> = 5.5V	-	-	-6	μA
Input current high (OEH)	I <sub>IH</sub>	V <sub>IN</sub> = 5.5V	V <sub>CC</sub> = 5.5V	-	-	6	μA





# CMOS Clock Generator – 74ACT3301A

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## DC Electrical Characteristics (+4.5V ≤ V<sub>CC</sub> ≤ +5.5 V, -40°C ≤ T<sub>J</sub> ≤ +85°C unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS	
			MIN	TYP	MAX		
Input current high (OSC_IN)	I <sub>IH</sub>	V <sub>IN</sub> = 5.5V V <sub>CC</sub> = 5.5V	20	-	125	μA	
Input current low (OSC_IN)	I <sub>IL</sub>	V <sub>IN</sub> = 0V V <sub>CC</sub> = 5.5V	-20	-	-125	μA	
Quiescent supply current, output low	I <sub>CCL</sub>	OE $\bar{H}$ = 5.5V, OEL = 0V, All other inputs V <sub>IN</sub> = V <sub>CC</sub> or GND	-	-	240	μA	
Quiescent supply current, output high	I <sub>CCH</sub>	V <sub>CC</sub> = 5.5V	-	-	45	μA	
Quiescent supply current, output three-state	I <sub>CCZ</sub>	OEH = 0V, OEL = 5.5V, All other inputs V <sub>IN</sub> = V <sub>CC</sub> or GND	-	-	45	μA	
Quiescent supply current delta, OSC_IN Floating	Δ I <sub>CCO</sub>	OSC_IN = Floating, all other inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND	OSC_DR = 0.45V V <sub>CC</sub> = 4.5V	0.6	-	-	mA
			OSC_DR = 0.55V V <sub>CC</sub> = 5.5V	-	-	6.5	mA
			OSC_DR = 4.05V V <sub>CC</sub> = 4.5V	1.7	-	-	mA
			OSC_DR = 4.95V V <sub>CC</sub> = 5.5V	-	-	12.4	mA
			OSC_DR = 1.8, 2.7V V <sub>CC</sub> = 4.5V	5.5	-	-	mA
			OSC_DR = 2.2, 3.3V V <sub>CC</sub> = 5.5V	-	-	31.5	mA
Quiescent supply current delta, input 3 level	Δ I <sub>CC3L</sub>	DIVB, OSC_DR = 2.75V, all other inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND	-	-	1.5	mA	
Quiescent supply current delta, TTL input level	Δ I <sub>CC<sup>T</sup>4</sub>	OEL, OEH = V <sub>CC</sub> - 2.1V, all other inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND	-	-	1.5	mA	

4. Performed one input at a time.







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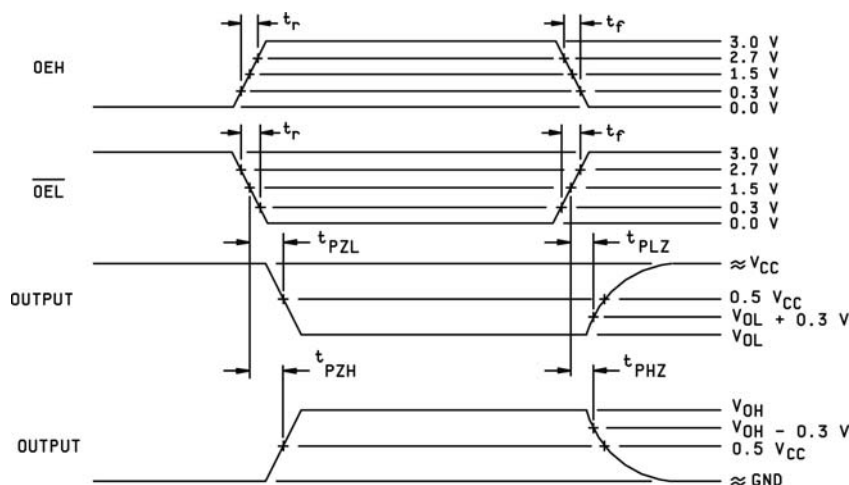
## DC Electrical Characteristics (+4.5V ≤ V<sub>CC</sub> ≤ +5.5 V, -40°C ≤ T<sub>J</sub> ≤ +85°C unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS	
			MIN	TYP	MAX		
Three-state output leakage current high	I <sub>OZH</sub>	V <sub>OUT</sub> = V <sub>CC</sub> , OEH = 0.8V, OEL = 2V, all other inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND	V <sub>CC</sub> = 4.5V	-	-	5	μA
			V <sub>CC</sub> = 5.5V	-	-	5	
Three-state output leakage current high	I <sub>OZL</sub>	V <sub>OUT</sub> = 0V, OEH = 0.8V, OEL = 2V, all other inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND	V <sub>CC</sub> = 4.5V	-	-	-150	μA
			V <sub>CC</sub> = 5.5V	-	-	-180	

## AC Electrical Characteristics (V<sub>CC</sub> = 5V ± 0.5V, T<sub>J</sub> = 25°C)

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
Frequency Maximum	f <sub>MAX</sub>	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500Ω	100	-	-	MHz
Output enable time, OEL or OEH to OUT	t <sub>PZH</sub>	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500Ω	1	-	31.5	ns
	t <sub>PZL</sub>		1	-	28.0	
Output disable time, OEL or OEH to OUT	t <sub>PHZ</sub>	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500Ω	1	-	21.5	ns
	t <sub>PLZ</sub>		1	-	16.0	
Rise / Fall time	t <sub>rise</sub> , t <sub>fall</sub>	C <sub>L</sub> = 30 pF (20% to 80%)	-	4	-	ns

## Switching Waveform

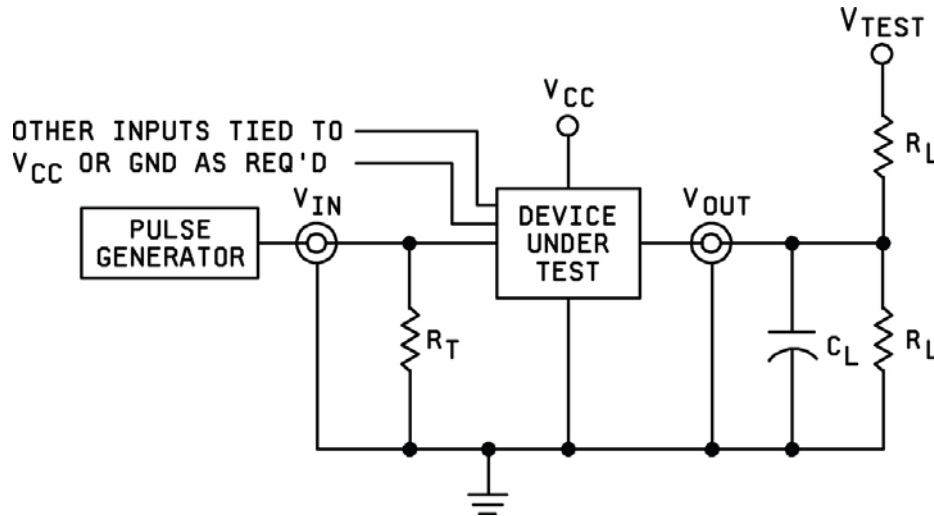




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## Test Circuit



1. When measuring  $t_{PLZ}$  and  $t_{PZL}$ :  $V_{TEST} = 2 \times V_{CC}$ .
2. When measuring  $t_{PHZ}$ ,  $t_{PZH}$ ,  $t_{PLH}$  and  $t_{PHL}$ :  $V_{TEST} = \text{open}$ .
3. The  $t_{PZL}$  and  $t_{PLZ}$  reference waveform is for the output under test with internal conditions such that the output is at  $V_{OL}$  except when disabled by the output enable control. The  $t_{PZH}$  and  $t_{PHZ}$  reference waveform is for the output under test with internal conditions such that the output is at  $V_{OH}$  except when disabled by the output enable control.
4.  $C_L = 50 \text{ pF}$  minimum or equivalent (includes test jig and probe capacitance).
5.  $R_L = 500\Omega$  or equivalent.
6.  $R_T = 50\Omega$  or equivalent.
7. Input signal from pulse generator:  $V_{IN} = 0.0 \text{ V}$  to  $3.0 \text{ V}$ ;  $PRR \leq 10 \text{ MHz}$ ;  $t_r \leq 3.0 \text{ ns}$ ;  $t_f \leq 3.0 \text{ ns}$ ;  $t_r$  and  $t_f$  shall be measured from  $0.3 \text{ V}$  to  $2.7 \text{ V}$  and from  $2.7 \text{ V}$  to  $0.3 \text{ V}$ , respectively; duty cycle = 50 percent.
8. Timing parameters shall be tested at a minimum input frequency of 1 MHz.

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